

Product data sheet

1 General description

The BGU8062 is, also known as the BTS3001M, a high linearity bypass amplifier for wireless infrastructure applications. The BGU8062 is equipped with fast shutdown to support TDD systems. The LNA has a high input and output return loss and is designed to operate between 1.5 GHz and 2.7 GHz. It is housed in a 3 mm × 3 mm × 0.85 mm 10-terminal plastic thin small outline package. The LNA is ESD protected on all terminals.

2 Features and benefits

- Low noise performance: NF = 1.3 dB
- High linearity performance: IP3_O = 36 dBm
- High input return loss > 12 dB
- High output return loss > 15 dB
- Unconditionally stable up to 20 GHz
- Small 10-terminal leadless package 3 mm × 3 mm × 0.85 mm
- ESD protection on all terminals
- Moisture sensitivity level 1
- · Fast shut down to support TDD systems
- +5 V single supply

3 Applications

- · Wireless infrastructure
- · Low noise and high linearity applications
- LTE, W-CDMA, CDMA, GSM
- General-purpose wireless applications
- TDD or FDD systems
- · Suitable for small cells



Quick reference data 4

Table 1. Quick reference data

 $f = 1900 \text{ MHz}; V_{CC} = 5 \text{ V}; T_{amb} = 25 \text{ °C}; input and output 50 \Omega; unless otherwise specified. All RF parameters are measured$ on an application board with the circuit as shown in Figure 29 and components listed in Table 9 implemented. This board is optimized for f = 1900 MHz.

Symbol	Parameter	Conditions	Mi	n	Тур	Max	Unit
I _{CC}	supply current	LNA enable; bypass off	-		70	85	mA
		LNA disable; bypass on	-		3	5	mA
G _{ass}	associated gain	LNA enable; bypass off	17		18.5	20	dB
		LNA disable; bypass on	-2.	0	-1.6	-	dB
NF	noise figure	LNA enable; bypass off	[1] _		1.3	2.0	dB
P _{L(1dB)}	output power at 1 dB gain compression	LNA enable; bypass off	18	.5	20	-	dBm
IP3 ₀	output third-order intercept point	2-tone; tone spacing = 1 MHz; P_L = 5 dBm per tone					
		LNA enable; bypass off	33	.5	36	-	dBm
		LNA disable; bypass on	^[2] 40		44	-	dBm

[1] [2] Connector and Printed-Circuit Board (PCB) losses have been de-embedded.

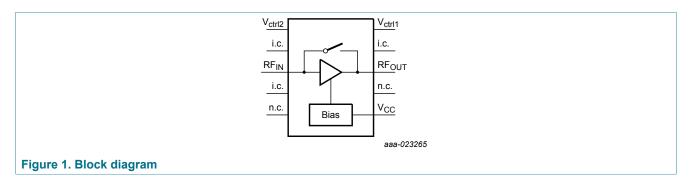
Guaranteed by device design; not tested in production.

Ordering information 5

Table 2. Ordering information

Type number	Package		
	Name	Description	Version
BGU8062	HVSON10	plastic thermal enhanced very thin small outline package;no leads; 10 terminals; body 3 \times 3 \times 0.85 mm	SOT650-2

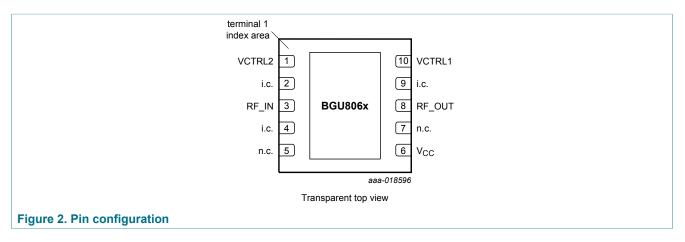
Block diagram 6



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7 Pinning information

7.1 Pinning



7.2 Pin description

Table 3. Pin description

	Table 5. Fin description					
Symbol	Pin	Description				
VCTRL2	1	voltage control 2				
i.c.	2, 4, 9	internally connected, can be grounded or left open in the application				
RF_IN	3	RF input				
n.c.	5	not connected				
V _{CC}	6	supply voltage				
n.c.	7	not connected				
RF_OUT	8	RF output				
VCTRL1	10	voltage control 1				
GND	exposed die pad	ground				

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8 Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). See Section 16.3 "Disclaimers", paragraph "Limiting values".

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-	6	V
V _{I(CTRL1)}	input voltage on pin CTRL1		-	3.6	V
V _{I(CTRL2)}	input voltage on pin CTRL2		-	3.6	V
P _{i(RF)CW}	continuous waveform RF input power		-	20	dBm
T _{stg}	storage temperature		-40	+150	°C
Tj	junction temperature		-	150	°C
Р	power dissipation	$T_{case} \le 125 \ ^{\circ}C$ ^[1]	-	510	mW
V _{ESD}	electrostatic discharge voltage	Human Body Model (HBM); according to ANSI/ESDA/JEDEC standard JS-001-2010	-	2.0	kV
		Charged Device Model (CDM); according to JEDEC standard 22-C101B	-	1.0	kV

[1] Case is ground solder pad.

9 Recommended operating conditions

Table 5. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CC}	supply voltage		4.75	5	5.25	V
Z ₀	characteristic impedance		-	50	-	Ω

10 Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R _{th(j-case)}	thermal resistance from junction to case	[1] [2]	55	K/W

[1] Case is ground solder pad.

[2] Thermal resistance measured using infrared measurement technique, device mounted on application board and placed in still air.

11 Characteristics

Table 7. Characteristics

f = 1900 MHz; $V_{CC} = 5 \text{ V}$; $T_{amb} = 25 \text{ °C}$; input and output 50 Ω ; unless otherwise specified. All RF parameters are measured on an application board with the circuit as shown in Figure 29 and components listed in Table 9 implemented. This board is optimized for f = 1900 MHz.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CC}	supply current	LNA enable; bypass off	-	70	85	mA
		LNA disable; bypass on	-	3	5	mA
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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
G _{ass}	associated gain	LNA enable; bypass off		18.5	20	dB
		LNA disable; bypass on	-2.0	-1.6	-	dB
		f = 2600 MHz; LNA enable; bypass off	14	15.5	17	dB
G _{flat}	gain flatness	within 100 MHz bandwidth; LNA enable; bypass off				
		 1500 MHz ≤ f ≤ 2700 MHz 	-	0.6	-	dB
		• 1900 MHz ≤ f ≤ 2700 MHz	-	0.5	-	dB
NF	noise figure	LNA enable; bypass off	1] -	1.3	2.0	dB
ΔG	gain variation	1900 MHz ≤ f ≤ 2700 MHz	-	3.1	-	dB
P _{L(1dB)}	output power at 1 dB gain compression	LNA enable; bypass off		20	-	dBm
IP3 ₀	output third-order intercept point	2-tone; tone spacing = 1 MHz; P _L = 5 dBm per tone				
		 LNA enable; bypass off 		36	-	dBm
		LNA disable; bypass on	^{2]} 40	44	-	dBm
RL _{in}	input return loss	LNA enable; bypass off	-	12	-	dB
		LNA disable; bypass on	-	15	-	dB
RL _{out}	output return loss		-	15	-	dB
ISL	isolation	LNA disable; bypass off	20	30	-	dB
		LNA enable; bypass off	15	20	-	dB
t _{s(pon)}	power-on settling time	P _i = -20 dBm	-	0.8	1.0	μs
t _{s(poff)}	power-off settling time	P _i = -20 dBm	-	0.8	1.0	μs
K	Rollett stability factor	both on state and off state up to f = 20 GHz	1	-	-	

[1] Connector and Printed-Circuit Board (PCB) losses have been de-embedded.

[2] Guaranteed by device design; not tested in production.

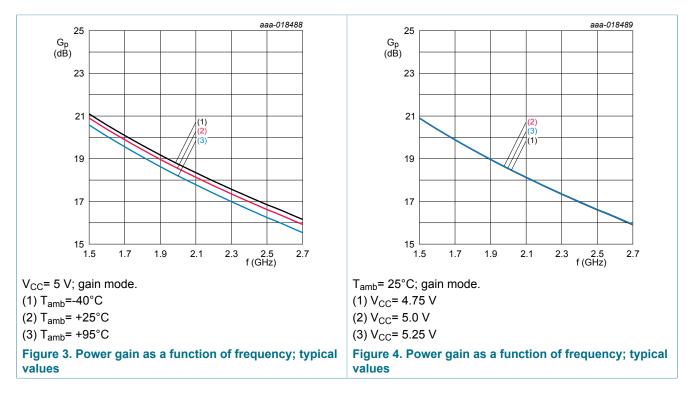
Table 8. Control truth table

 V_{CC} = 5 V; T_{amb} = 25 °C.

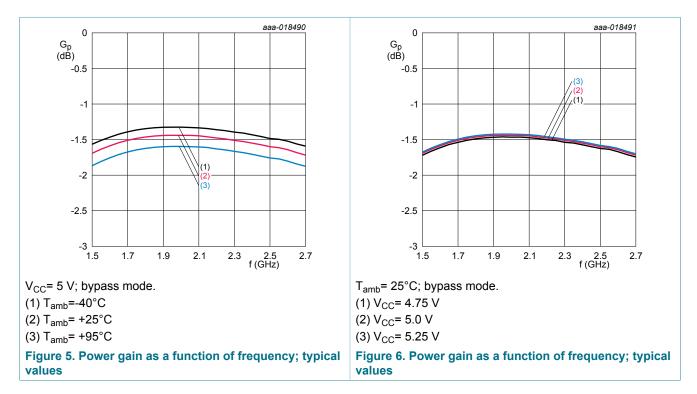
Control signal setting ^[1]		Mode of operation		
CTRL2 (pin 1)	CTRL1 (pin 10)	LNA	bypass	
HIGH	LOW	disable	on	
HIGH	HIGH	disable	on	
LOW	LOW	enable	off	
LOW	HIGH	disable	off	

 A logic LOW is the result of an input voltage on that specific pin between -0.3 V and +0.7 V. A logic HIGH is the result of an input voltage on that specific pin between 1.2 V and 3.6 V.

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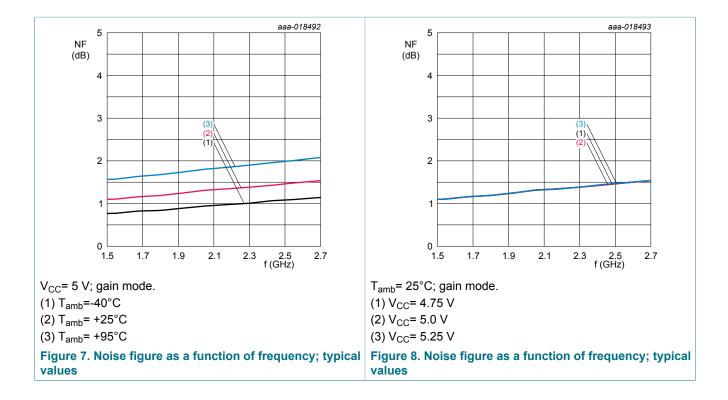


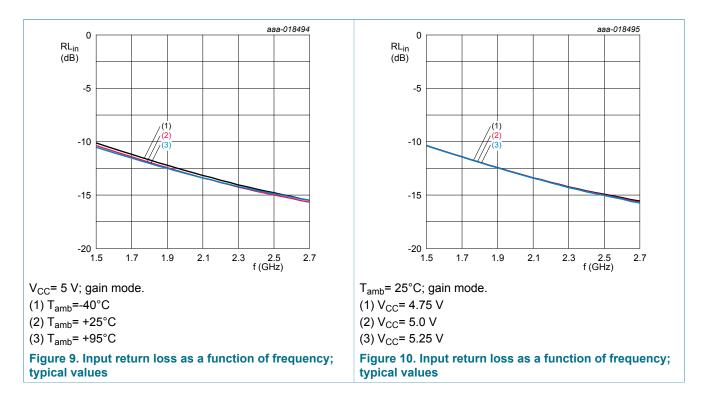
11.1 Graphs



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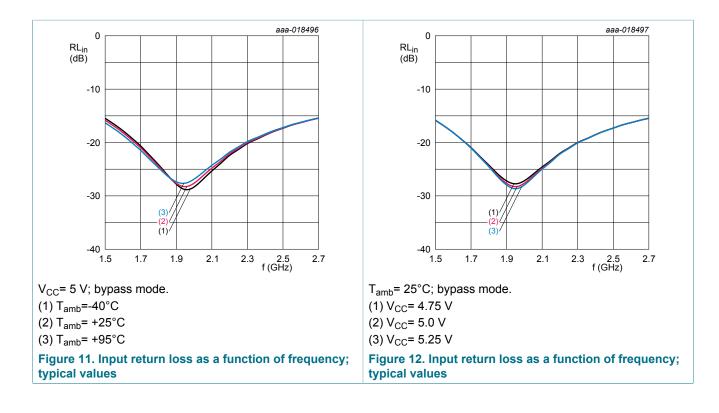


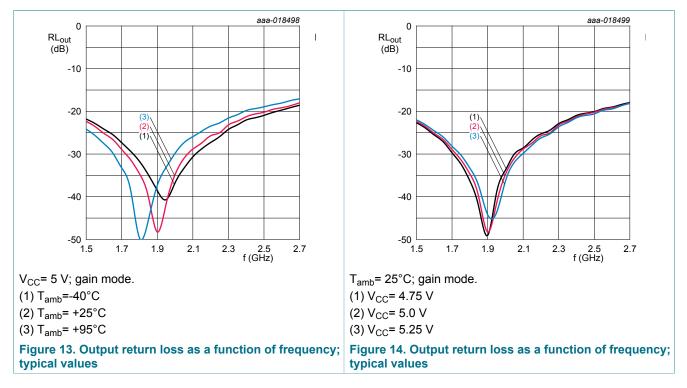


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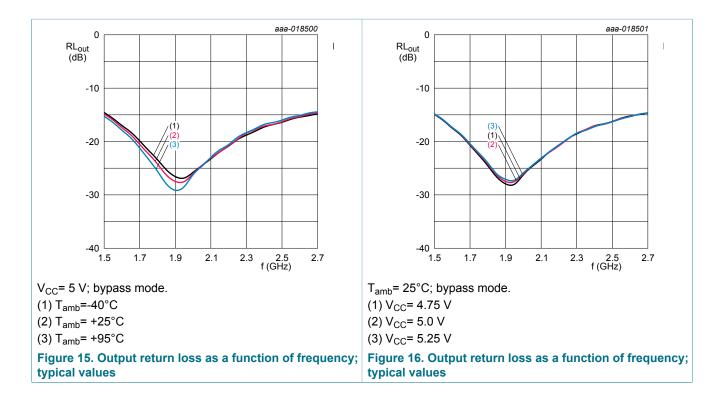


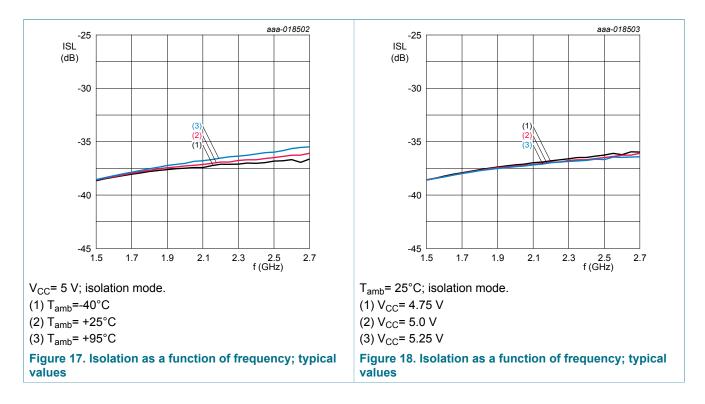


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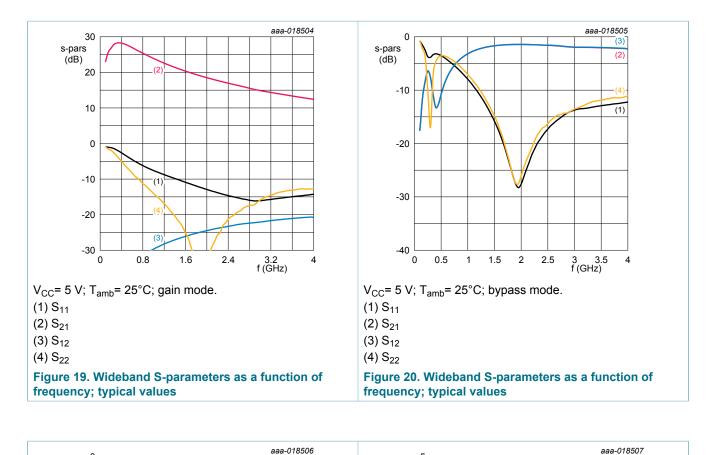


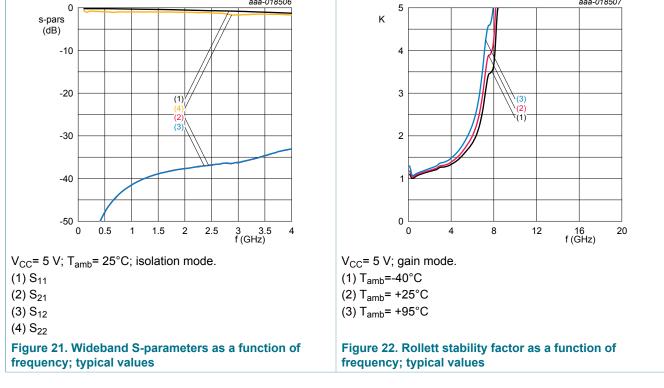


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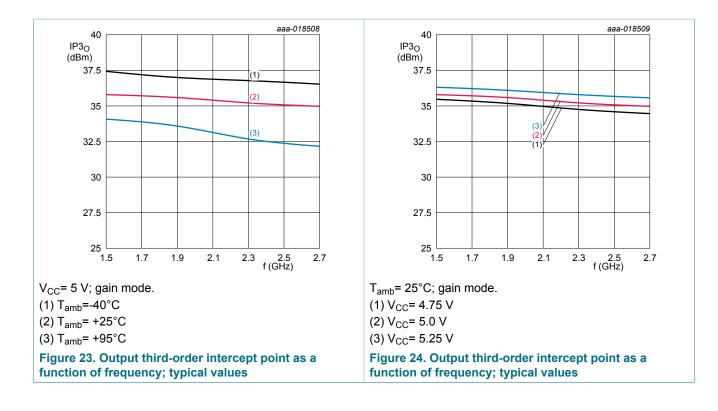
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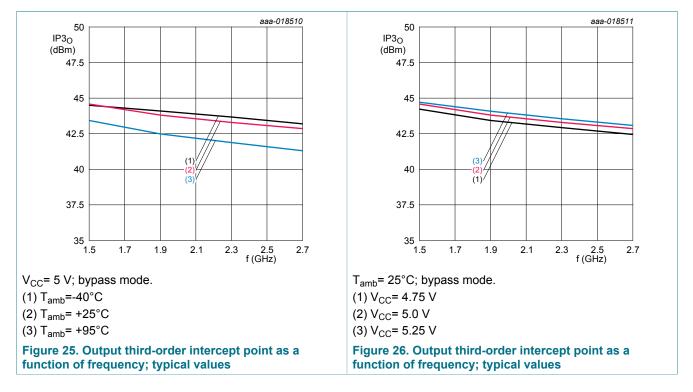




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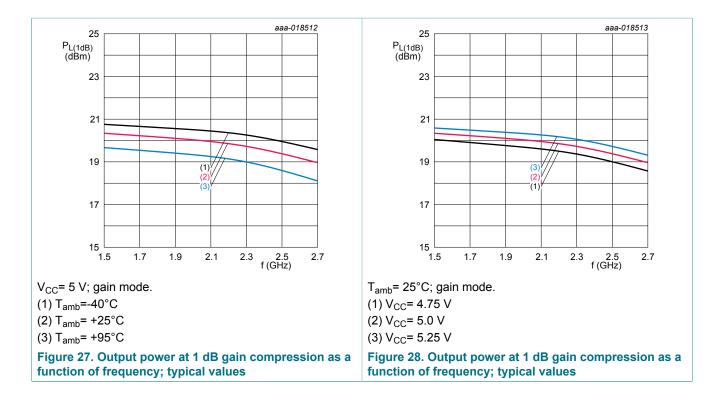
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12 Application information

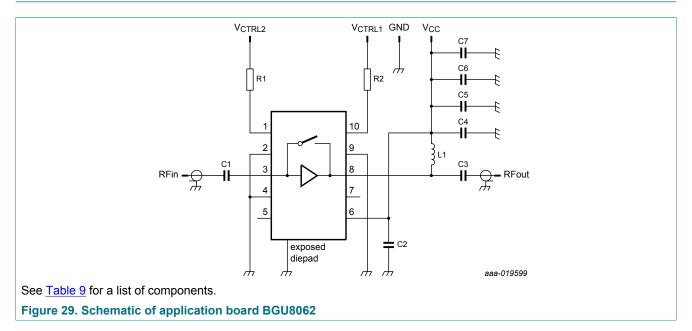


Table 9. List of components

See Figure 29 for schematics.

Component	Description	Value	Remarks	
C1	capacitor	100 nF		
C2, C3	capacitor	100 pF		
C4	capacitor	1 nF		
C5	capacitor	-	optional	
C6	capacitor	10 nF		
C7	capacitor	1 µF		
L1	inductor	15 nH		
R1, R2	resistor	1 kΩ		

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13 Package outline

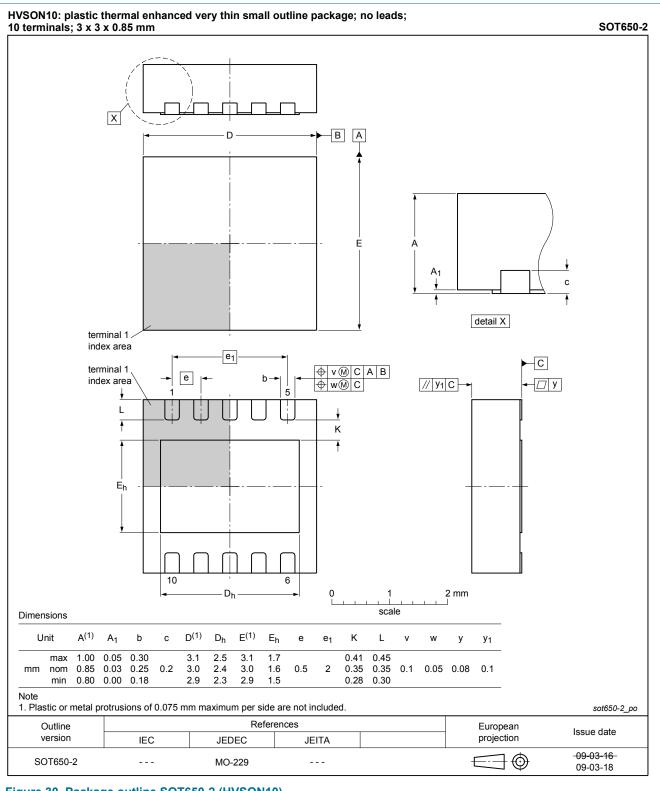


Figure 30. Package outline SOT650-2 (HVSON10)

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14 Abbreviations

Table 10. Abbreviations					
Acronym	Description				
CDMA	Code Division Multiple Access				
ESD	ElectroStatic Discharge				
FDD	Frequency-Division Duplexing				
GSM	Global System for Mobile Communication				
LNA	Low Noise Amplifier				
LTE	Long Term Evolution				
TDD	Time-Division Duplexing				
W-CDMA	Wideband Code Division Multiple Access				

15 Revision history

Table 11. Revision history							
Document ID	Release date	Data sheet status	Change notice	Supersedes			
BGU8062 v.2	20170124	Product data sheet	-	BGU8062 v.1			
Modifications:	 Table 1 added: Min value to IP3_O added BTS3001M according to our new naming convention 						
BGU8062 v.1	20150909	Product data sheet	-	-			

16 Legal information

16.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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